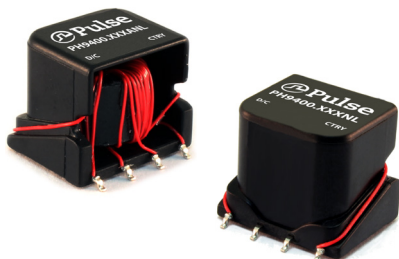
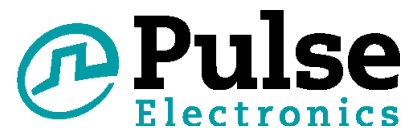


High Isolation Gate Drive Transformers

PH9400.XXXNL and PH9400.XXXANL - SMT



-  Basic and Reinforced Insulation
-  Patent Pending Sidecar package with 12mm creepage
-  Up to 5000Vrms gate to drive isolation
-  600Vrms continuous isolation between windings

Electrical Specifications @ 25°C - Operating Temperature -40°C to +125°C

Part Number	Turns Ratio	ET (V * μsec MAX)	Core Loss Factor K1	Primary Inductance (1-4) (mH +/-35%)	Leakage Inductance Drive to Gate (μH MAX)	Parasitic Capacitance Drive to Gate (pF MAX)	DCR Drive (1-4) (Ω MAX)	DCR Gates (5-6) (7-8) (Ω MAX)	Hi-Pot	
									Drive-Gate (Vrms)	Gate-Gate (Vrms)
PH9400.XXXNL - Basic Insulation										
PH9400.111NL	1:1:1	315	0.67	4.5	5.0	60	1.8	2.5	4000	1500
PH9400.566NL	5:6:6	315	0.67	4.5	3.5	60	1.8	3.0	4000	1500
PH9400.122NL	1:2:2	250	0.84	2.88	3.5	60	1.5	4.2	4000	1500
PH9400.655NL	6:5:5	375	0.56	6.48	5.3	60	2.2	2.5	4000	1500
PH9400.211NL	2:1:1	375	0.56	6.48	8.0	60	2.2	1.6	4000	1500
PH9400.XXXANL - Reinforced Insulation										
PH9400.111ANL	1:1:1	160	1.32	1.21	2.5	45	0.9	0.9	5000	2000
PH9400.566ANL	5:6:6	155	1.36	1.12	3.0	45	0.9	1.0	5000	2000
PH9400.233ANL	2:3:3	125	1.68	0.72	2.0	45	0.7	1.0	5000	2000
PH9400.655ANL	6:5:5	185	1.14	1.62	3.0	45	1.0	0.9	5000	2000
PH9400.211ANL	2:1:1	185	1.14	1.62	3.5	45	1.0	0.55	5000	2000

Notes:

- The max ET is calculated to limit the core loss and temperature rise at 100kHz based on a bipolar flux swing of 2100Ga Peak. This value needs to be derated for higher frequencies using the temperature rise calculation.
- The temperature rise of the component is calculated based on the total core loss and copper loss:
 - To calculate total copper loss (W), use the following formula:

$$\text{Copper Loss (W)} = I_{rms}^2 * (\text{DCR_Drive} + (\# \text{ of Gates}) * \text{DCR_Gates})$$
 - To calculate total core loss (W), use the following formula:

$$\text{Copper Loss (W)} = 5.1E-10 * (\text{Frequency in kHz})^{1.42} * (K1 * ET)^{2.5}$$

Where $ET = (V * \text{Duty Cycle}) / \text{Frequency}$
 - To calculate temperature rise, use the following formula:

$$\text{Temperature Rise (C)} = 71 * (\text{Core Loss(W)} + \text{Copper Loss (W)})$$
- Continuous isolation voltage confirmed by 125°C/1000hrs accelerated aging with the bias voltage applied between gate and drive windings.
- ANL versions, which use triple insulated wire on both the drive and gate windings, are compliant with IEC 60950, IEC 61558, IEC 61010 & IEC 60601 for reinforced insulation. NL versions, which use triple insulated wire on just the drive winding, comply with basic insulation requirements.
- 12mm package creepage distance satisfies IEC60950-1 & IEC61558-1/-2-16 reinforced insulation requirements for working voltage to 600Vrms max, OVC II, Pollution Degree 2 and altitude up to 2000m.
- Unless otherwise specified, all testing is made at 100kHz, 0.1V_{AC}.
- Optional Tape & Reel packaging can be ordered by adding a "T" suffix to the part number (i.e. PH9400.111NL becomes PH9400.111NLT). Pulse complies to industry standard tape and reel specification EIA481.

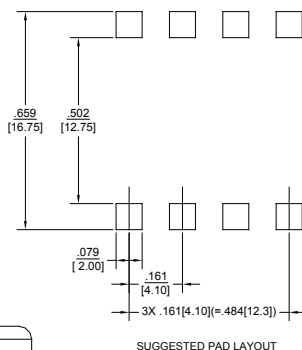
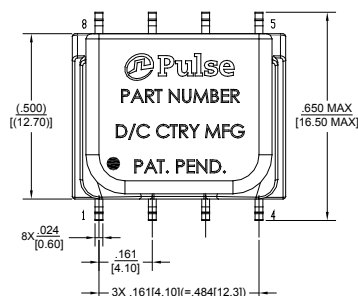
High Isolation Gate Drive Transformers

PH9400.XXXNL and PH9400.XXXANL - SMT

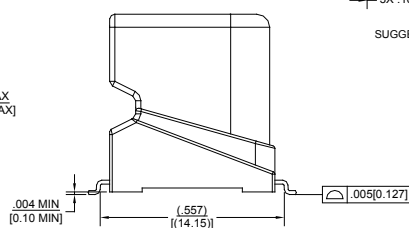
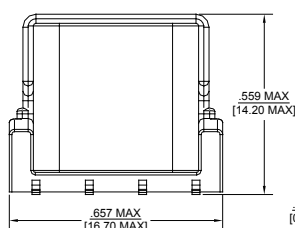
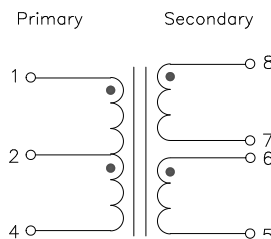
Mechanicals

Schematics

PH9400.XXXNL and PH9400.XXXANL



PH9400.XXXNL/PH9400.XXXANL



Weight 2.5 grams

Tape & Reel 150/Reel

Tray 80/tray

Dimension: $\frac{\text{Inches}}{\text{mm}}$

Unless otherwise specified, all tolerances are $\pm \frac{.010}{0.25}$

For More Information

Pulse Worldwide Headquarters

12220 World Trade Drive
San Diego, CA 92128
U.S.A.

Tel: 858 674 8100
Fax: 858 674 8262

Pulse Europe

Pulse Electronics GmbH
Am Rottland 12
58540 Meinerzhagen
Germany

Tel: 49 2354 777 100
Fax: 49 2354 777 168

Pulse China Headquarters

B402, Shenzhen Academy of
Aerospace Technology Bldg.
10th Kejian Road
High-Tech Zone
Nanshan District
Shenzhen, PR China 518057

Tel: 86 755 33966678
Fax: 86 755 33966700

Pulse North China

Room 2704/2705
Super Ocean Finance Ctr.
2067 Yan An Road West
Shanghai 200336
China

Tel: 86 21 62787060
Fax: 86 2162786973

Pulse South Asia

135 Joo Seng Road
#03-02
PM Industrial Bldg.
Singapore 368363

Tel: 65 6287 8998
Fax: 65 6287 8998

Pulse North Asia

3F, No. 198
Zhongyuan Road
Zhongli City
Taoyuan County 320
Taiwan R. O. C.
Tel: 886 3 4356768
Fax: 886 3 4356823 (Pulse)
Fax: 886 3 4356820 (FRE)

Performance warranty of products offered on this data sheet is limited to the parameters specified. Data is subject to change without notice. Other brand and product names mentioned herein may be trademarks or registered trademarks of their respective owners. © Copyright, 2016. Pulse Electronics, Inc. All rights reserved.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9